

BETAVOLTAIC POWER SOURCES FOR MOBILE DEVICE APPLICATIONS

CLAIM OF PRIORITY

[0001] This Application claims priority under 35 USC § 119(e) from U.S Provisional Patent Application Serial No. 61/637,396, filed on April 24, 2012, and which is incorporated by reference herein.

FIELD

[0002] The present disclosure relates generally to power sources, and more generally to betavoltaic power sources for mobile device applications.

BACKGROUND ART

[0003] As society becomes increasingly more dependent upon mobile devices (such as cell and smart phones, laptops, tablets, medical devices, and like hand-held and portable devices), high-power energy storage devices (such as batteries) are becoming increasingly in demand. An ideal battery for such devices would be designed to store sufficient energy to last for the useful life of the particular device, which lifetime could range from months to several years depending on the nature of the product (e.g. disposable cell phone, laptop computer, etc.).

[0004] For example, a cell phone typically draws between about 100 to 500 mw of power during operation, but an average battery can only store sufficient energy to drive the cell phone for approximately a day. The average cell phone battery stores roughly 1-5 watt-hours of energy which is typically dissipated during one day of average.

[0005] Similarly, tablet batteries store roughly 40-50 watt-hours of energy and last up to about 10 hours, indicating that the average power consumption is roughly 5 watts. Laptop computer batteries store roughly 75 watt-hours of energy and last approximately 5 hours, indicating that the average power consumption is roughly 15 watts. At the end of these time periods, it is necessary to recharge the battery to continue to use the device.

[0006] The average lifetime of a cell (or smart) phone is roughly 2 years. The lifetime of medical devices can range from one to several years. The average lifetime of a laptop (and by association, a tablet) is roughly 3 years.

[0007] Isotope-based power sources have been used to power certain types of electrical devices. For example, some isotope-based power generators convert the energy of alpha particles emitted from radioactive material into heat, which is then converted into useful energy like electricity. This is a thermoelectric conversion and is commonly used to power electrical devices used on deep space missions. In general, alpha particles used in this approach are fairly energetic (over 1 MeV) and can damage transistors. Hence, alpha-particle emitters are best used to create heat (by capturing the particle in a suitable material, such as a ceramic) and then converting that heat into electricity.

[0008] Another type of isotope-based power source converts the emission of beta-particles (electrons) into electricity. These are sometimes called betavoltaics. An example of a prior art betavoltaic power source is described in the article "Technology Today," issue #1, 2011, and published at http://www.raytheon.com/technology_today/2011_i1/power.html.

[0009] Betavoltaic power sources have historically been useful where low power (tens of microwatts) is needed over many years (tens to hundreds of years). This is essentially a "solar cell" device (usually called a photovoltaic because it reacts to photons), but instead of using photons to create electron-hole pairs, the emitted "betas" (or high energy electrons) from the isotope create the hole-electron pairs. Betavoltaic power sources are used for deep space missions to produce energy at a few tens of a microwatt. For applications, which requires a life time of tens of years, the half-life of the isotope is often several decades, and (63)Ni with a half-life of 100 years is a preferred material.

[0010] Another use of isotope-based power sources is in the medical field where a low-power device (such as a pacemaker) is placed inside a patient. The pacemaker is generally inaccessible, and a long-life power source is advantageous. Because these devices are implanted within a patient, the total amount of emitted radiation must be very low, which in turn requires that the amount of power generated is low. For this application, the isotope thermoelectric generator has proven to be a successful product.

[0011] It would be desirable to have an isotope-based electrical power source that can generate sufficient power to drive a mobile device for the useful lifetime of the device without the need for recharging.

SUMMARY

[0012] The present disclosure is directed to betavoltaic power sources for powering mobile devices. The betavoltaic power source provides continuous operation for a span of time that corresponds to about the useful lifetime of the mobile device.

[0013] The betavoltaic power source disclosed herein relies upon nuclear reactions associated with isotopes to convert stored energy to electricity. Betavoltaic power sources traditionally work on converting beta (electron) particles to energy using a very long-lived isotope. They are used for low-power applications, and where accessibility to the device is impractical, such as spacecraft and satellites.

[0014] The betavoltaic power sources disclosed herein can be configured to provide a select amount of power suitable for a given mobile device that has a useful lifetime. The integration of select isotopes with a stacking (multilayer) architecture of isotope material and energy conversion material provides power levels that are orders of magnitude higher than prior art betavoltaic power sources. The beta particles (“betas”), as well as x-rays and gamma rays (“gammas”) are converted into useful electricity to drive mobile devices.

[0015] An aspect of the disclosure is a betavoltaic power source for a mobile device having a useful lifetime. The source includes a plurality of isotope layers, with each isotope layer comprising an isotope material that emits radiation as either beta particles, x-rays or gamma rays having an amount of energy that is greater than about 15 keV and less than about 200 keV, and a half-life that is between about 0.5 years and about 5 years. The source also includes a plurality of energy conversion layers interposed between some or all the isotope layers and that receive and convert the energy from the radiation into electrical energy sufficient to power the mobile device over the useful lifetime.

[0016] Another aspect of the disclosure is the betavoltaic power source as described above, wherein the energy conversion layers comprise GaN.

[0017] Another aspect of the disclosure is the betavoltaic power source as described above, wherein the energy conversion layers each have a thickness of about 10 microns to 20 microns.

[0018] Another aspect of the disclosure is the betavoltaic power source as described above, wherein the isotope material is selected from the group of isotope materials comprising: (3)H, (194)Os, (171)Tm, (179)Ta, (109)Cd, (68)Ge, (159)Ce, and (181)W.

[0019] Another aspect of the disclosure is the betavoltaic power source as described above, and further including a radiation-absorbing shield operably arranged to substantially prevent the beta particles, x-rays and gamma rays from exiting the betavoltaic power source.

[0020] Another aspect of the disclosure is the betavoltaic power source as described above, wherein adjacent isotope and energy conversion layers define layer pairs and wherein the betavoltaic power source includes between 10 and 250 layer pairs.

[0021] Another aspect of the disclosure is the betavoltaic power source as described above, wherein the isotope layers are formed from the same isotope material.

[0022] Another aspect of the disclosure is the betavoltaic power source as described above, wherein the amount of electrical energy is at least 10 mw.

[0023] Another aspect of the disclosure is the betavoltaic power source as described above, wherein the amount of electrical energy is at least 100 mw.

[0024] Another aspect of the disclosure is the betavoltaic power source as described above, and further including cooling conduits that remove heat from the isotope and energy conversion layers.

[0025] Another aspect of the disclosure is the betavoltaic power source as described above, and further comprising the mobile device electrically connected to the betavoltaic power source.

[0026] Another aspect of the disclosure is a betavoltaic power source for a mobile device. The source includes a plurality of isotope layers, with each isotope layer comprising an isotope material that emits radiation having an amount of energy that is greater than about 15 keV and less than about 200 keV, and a half-life that is between about 0.5 years and about 5 years. The source also includes a plurality of energy conversion layers interposed between some or all the isotope layers and that receive and convert the energy

from the radiation into electrical energy of no less than 10 mw to power the mobile device over a useful lifetime of between 0.5 years and 5 years.

[0027] Another aspect of the disclosure is the betavoltaic power source as described above, wherein one or more of the energy conversion layers have a diode structure.

[0028] Another aspect of the disclosure is the betavoltaic power source as described above, wherein the diode structure includes either GaN or Ge.

[0029] Another aspect of the disclosure is the betavoltaic power source as described above, wherein the Ge comprises (68)Ge.

[0030] Another aspect of the disclosure is the betavoltaic power source as described above, wherein adjacent isotope and energy conversion layers define layer pairs, and wherein the betavoltaic power source includes between 10 and 250 layer pairs.

[0031] Another aspect of the disclosure is the betavoltaic power source as described above, wherein the isotope layers are formed from first and second isotopes having different half-lives.

[0032] Another aspect of the disclosure is the betavoltaic power source as described above, wherein the radiation includes at least one of beta particles, x-rays and gamma rays.

[0033] Another aspect of the disclosure is the betavoltaic power source as described above, and further including the mobile device.

[0034] Another aspect of the disclosure is the betavoltaic power source as described above, and further including a conventional battery electrically connected to the betavoltaic power source.

[0035] It is to be understood that both the foregoing general description and the following detailed description presented below are intended to provide an overview or framework for understanding the nature and character of the disclosure as it is claimed. The accompanying drawings are included to provide a further understanding of the disclosure, and are incorporated into and constitute a part of this specification. The drawings illustrate various embodiments of the disclosure and together with the description serve to explain the principles and operations of the disclosure.

BRIEF DESCRIPTION OF THE DRAWINGS

[0036] FIGS. 1, 2, 3, 4A and 4B are schematic diagrams of example embodiments of the betavoltaic power source of the present disclosure;

[0037] FIG. 5 is a schematic diagram of an example mobile device (e.g., a smart phone) with the betavoltaic power source of the present disclosure;

[0038] FIGS. 6A and 6B show side and top views, respectively, of an example embodiment of an energy conversion layer formed as a diode;

[0039] FIG. 7A shows a side view two diode-based energy conversion layers operably arranged relative to the isotope layer;

[0040] FIG. 7B shows the same device as in FIG. 7A, but rotated 90 degrees to illustrate an example configuration of the electrodes of the diode-based energy conversion layer;

[0041] FIG. 7C is similar to FIG. 7B and shows the electrodes electrically connected to an external mobile device; and

[0042] FIG. 8 is similar to FIG. 3 and illustrates the use of $(68)\text{Ge}$ as the energy conversion layer in the betavoltaic power source.

DETAILED DESCRIPTION

[0043] Reference is now made in detail to various embodiments of the disclosure, examples of which are illustrated in the accompanying drawings. Whenever possible, the same or like reference numbers and symbols are used throughout the drawings to refer to the same or like parts. The drawings are not necessarily to scale, and one skilled in the art will recognize where the drawings have been simplified to illustrate the key aspects of the disclosure.

[0044] The claims as set forth below are incorporated into and constitute part of this Detailed Description.

[0045] The abbreviation “mw” as used herein means “milliwatts.”

[0046] Isotopes are denoted herein as $(x)y$, with x being the mass number and y the element symbol.

[0047] The term “radiation” is used herein in the context of radioactivity of an isotope and includes both emitted particles and electromagnetic waves.

[0048] The term “betavoltaic” as used herein is not limited to beta particles, and includes other non-beta radiation, such as gamma rays and x-rays. Thus, the term “betavoltaic power source” as used herein is synonymous with “isotope-based power source,” since these two terms are often used synonymously.

[0049] Any patent application or publication cited herein is incorporated herein by reference, including the following U.S. Patents, patent publication, and published articles and presentations: 7,301,254; 7,622,532; 7,663,288; 7,939,986; 8,017,412; 8,134,216; 8,153,453; 2011/0031572; Hornsberg et al., “GaN betavoltaic energy converters,” 0-7803-8707-4/05, 2005 IEEE; Presentation by the Arlington Technology Association, entitled “The BetaBattery™ – A long-life, self-recharging battery,” March 03, 2010; The presentation by Larry L. Gadekan, “Tritiated 3D diode betavoltaic microbattery,” IAEA advanced Workshop, Advanced Sensors for Safeguards, 23-27 April 2007.

[0050] The present disclosure is directed to betavoltaic power sources for mobile devices and mobile applications. There are certain types of power sources that utilize isotopes wherein one or more thin layers of isotope material (isotope layer) is/are surrounded by an energy conversion material (energy conversion layer). The energy conversion layer acts like a generator. In general, it receives radiation from the isotope and converts the energy of the radiation into useful electricity, i.e., an amount of electric current that represents a corresponding amount of electrical power.

[0051] The present disclosure sets forth example betavoltaic power sources that can produce at least 10 mw, and in preferred examples, from hundreds of mw to several watts, and which are suitable for mobile devices such as laptops and cell phones. Example useful lifetimes for such devices is from 3 months to 10 years or 0.5 years to 5 years.

[0052] FIG. 1 is a schematic diagram of an example betavoltaic power source 6 that has a stacked structure defined by energy conversion layers (films) 10 and isotope layers (films) 20. The energy conversion layers 10 are interposed between some or all of the isotope layers 20. In an example such as shown in FIG. 1, the stacked structure includes alternating energy conversion layers 10 and isotope layers 20.

[0053] In an example, the material making up energy conversion layers 10 includes or consists of GaN, while the material making up isotope layers includes or consists of (179). Thus, in an example embodiment, betavoltaic power source 6 has a stacked structure defined by GaN/(179)Ta/GaN/(179)Ta /GaN/(179)Ta /...../GaN, with each energy conversion layer 10 being approximately 10 microns to 20 microns thick. Thus, in an example, the stacked structure of betavoltaic power source 6 is defined by a sequence of alternating “layer-pairs” 30 of layers 10 and 20.

[0054] The specific design of betavoltaic power source 6 disclosed herein is based on a number of basic requirements for a powering a mobile device:

- 1) A life time that is comparable to (and perhaps a little longer than) the lifetime of the mobile device;
- 2) Sufficient average power generation to meet consumer needs; and
- 3) Environmentally safe and consumer friendly, i.e., does not emit radiation that is harmful to humans, the environment or to any adjacent electronics.

[0055] Isotopes have a known half-life. In addition, the emission from the decay process is generally known. The emission from decaying isotopes generally falls into the following categories:

- 1) Gamma radiation (gammas): This is radiation whose source is the nucleus of the atom. The energy of the radiation is measured in keV.
- 2) X-ray radiation: This is radiation whose source is the electrons surrounding the atom. The energy of the radiation is measured in keV.
- 3) Beta emission (betas): A “beta” is an ejected electron from the atom. The energy of the electron is measured in keV.
- 4) Alpha emission (alphas): An “alpha” particle is an ejected helium atom. The energy of the “alpha” particles is measured in keV.

[0056] Note that gamma radiation and x-ray radiation is essentially the same (both are electromagnetic radiation), except that the source of the radiation is different. Gammas come from the nucleus of an atom and x-rays come from the orbiting electrons of an atom.

[0057] The example betavoltaic power sources 6 disclosed herein converts at least one of betas, gammas and x-rays into useful energy, and in particular into electrical energy. In

an example, GaN-type or Ge-type energy conversion layers 10 are used. In an example, energy conversion layers 10 of different materials are used. Also in an example, different isotope layers 20 are used.

[0058] The power created by a betavoltaic power source is proportional to the number of emitted particles per unit time from the isotope, which in turn depends upon the number of isotope atoms and the half-life of the isotope. When the isotope layer is “fully converted” (i.e., is undiluted by the presence of other materials), then the energy stored in the isotope layer is maximized.

[0059] The only way to increase the power created by a betavoltaic power source is to decrease the half-life of the isotope, thereby increasing the number of emitted particles per unit time, since the number of source atoms in the isotope layer is constant. Therefore, for higher-power and relatively short-lifetime devices (e.g., up to a ten years or just a few years, or just a few months, and not tens of years), isotopes having correspondingly shorter half-lives are required.

[0060] As most consumer mobile devices have a lifetime that can range from a few months to a ten years (with most having a maximum lifetime of just a few years), isotopes with a half-life of similar duration are considered herein, with a specific example half-life being in the range from about 0.5 years to about 5 years. By starting off with an isotope that has a shorter half-life than (^{63}Ni) (and assuming both isotope layers are fully converted), the number of emitted particles per unit time can be increased by the ratio of the half-lives.

[0061] Also in an example, the betavoltaic power sources 6 disclosed herein utilize an isotope whose emission would not be hazardous to a user. For gammas and x-ray emissions, example isotopes for use in isotope layer 20 have energies less than approximately 250 keV or even less than 200 keV.

[0062] In the betavoltaic power sources disclosed herein, the isotopes can emit betas, x-rays or gammas. Both x-rays and gammas can create hole and electron pairs in GaN material and assist in the energy creation. In an example, more than one type of isotope is used. In an example, at least one of electrons (betas), x-rays and gammas are employed.

[0063] Example criteria for the material used for the isotope layers 20 include the following :

- 1) A short half-life that substantially matches the useful life of the mobile device or application;
- 2) Emission of the requisite amount of stored energy in order to provide the requisite amount of electrical power during that useful life time.
- 3) emits betas, gammas or x-rays with energies less than 250 keV.
- 4) emits betas, gammas and x-rays with energies greater than 15 keV.
- 5) Does not emit alpha particles.

[0064] Criterion 1 above requires extracting all the energy out of the isotope layer 20 in a time that is similar to the useful lifetime of the mobile device. This ensures the maximum power is available from betavoltaic power source 6. Criterion 2 ensures that the mobile device will have sufficient electrical power. Criterion 3 ensures that the emission from the isotope layer 20 can be used effectively without significant harmful side-effects to either the mobile device or to humans. Criterion 4 is to ensure that the emission produces a useful minimum amount of power. Criterion 5 avoids the aforementioned disadvantages of energetic alpha particles.

[0065] Another criterion is that the energy conversion layers 10 be made of a III-IV type compound to make the betavoltaic power source 6 radiation-hardened. It is known that silicon devices, with their smaller bandgap, are more prone to damage from high-energy radiation and/or betas, whereas GaN or AlGaIn devices are far more damage resistant.

[0066] In an example, it is preferred that the isotope material can be artificially created.

[0067] The Table below sets forth example isotopes and their half-lives, emission energy and mode of production. Notice that the columns for the emitted species list the maximum energy for that species. Typically, the emission is a continuum. For example, for (179)Ta, the maximum x-ray emission is 65 keV. However, there is a continuum of emission from 6 keV to 65 keV. The lower energy x-rays are particularly useful for creating electricity.

Isotope	half-life (Years)	Max Gamma (keV)	Max x-ray (keV)	Max Beta (keV)	Known Production Modes
<u>3H</u>	12.3			18.6	Charged particle and thermal neutron activation
<u>(194)Os</u>	6.0	82	75	87	Thermal neutron activation
(228)Ra	5.76	31	19	40	Naturally occurring
(155)Eu	4.76	146	50	252	Fast and Thermal neutron activation
(147)Pm	2.63	197	46	224	Fast and Thermal neutron activation
<u>(171)Tm</u>	1.92	67	61	96	Fast and Thermal neutron activation
(172)Hf	1.87	202	63	284	Charged particle reaction
<u>(179)Ta</u>	1.82	65	none	111	Photon and fast neutron activation
<u>(109)Cd</u>	1.27	88	25	126	Fast and Thermal neutron activation
(106)Ru	1.02	None	none	39.4	Fission by product
<u>(68)Ge</u>	0.74	None	10.4	106	Charged particle reaction
(195)Au	0.51	211	78	226	Charged particle and fast neutron activation
(45)Ca	0.45	12.4	4.5	257	Fast and Thermal neutron activation
<u>(139)Ce</u>	0.38	166	39	112	Fast and Thermal neutron activation
<u>(181)W</u>	0.33	152	67	188	Fast and Thermal neutron activation

[0068] From the above list of isotopes and the criteria set forth above, the underlined and bold isotopes in the Table are potentially best suited for use as isotope layers 20.

[0069] Other isotopes in the above Table may be used under more select circumstances. For example, those isotopes that emit higher-energy betas can still work, but may create more damage in a GaN-based energy conversion layer 10. Isotopes that emit gammas that are very high in energy will require additional shielding. Isotopes that have no known artificial manufacturing process will have limited availability. Isotopes that are a product of fission may also have limited availability.

[0070] For mobile devices with expected useful lifetimes of approximately 10 years, it may be desirable to use ³H for isotope layers 20. Because ³H (deuterium) is not a solid, in an example embodiment the deuterium isotope layer 20 comprises deuterium combined with another material to make the isotope layer solid.

[0071] For mobile devices with a useful lifetime of about 5 years, (194)Os is a desirable isotope choice.

[0072] For mobile devices with a useful lifetime of about 2 years, (179)Ta is a desirable isotope choice.

[0073] For mobile devices with a useful lifetime of less than 1 year, (68)Ge is a desirable isotope choice.

[0074] Thus, all of the isotopes listed above are potentially useful for isotope layers 20, though some will be easier to work with and involve less expense.

Electrical current and power calculations

[0075] In order to assess how much electrical current and electrical power can be generated by betavoltaic power source 6, assume an isotope layer 20 that is a 10 micron thick layer of (179)Ta, with a half-life of 1.82 years. Further assume that 100% of the layer is converted to isotopes. The (179)Ta isotope layer 20 emits 65 keV gammas and 111 keV betas. The betas will be effectively absorbed in 10 to 20 microns of GaN. The absorption length of 65 keV gammas in GaN will be over 100 microns, so that most of the gammas will not be absorbed for the 10 to 20 microns thick GaN layer. The fraction of gammas that are absorbed will add to the production of electrical power.

[0076] The estimated number of disintegrations per second from a 10 micron thick layer (and an area of 1 cm²) of (179)Ta is approximately 1x10¹² per second. This is computed from the calculated number of atoms in the film, half of which will disintegrate during the half-life, divided by the half-life in seconds. The number of electron-hole pairs generated in the conversion material is given by:

$$G = (N \cdot E) / E_{ehp}$$

where G is the number of electron-hole pairs generated, N is the number of disintegrations per second, E is the beta particle energy and E_{ehp} is the average energy that it takes to generate an electron-hole-pair.

[0077] For 1x10¹² disintegrations per second, about 1 milliamp of current is generated from the 1 cm² isotope layer 20. Assuming a GaN energy conversion layer 10 that is 10 microns thick, the open circuit voltage is roughly 2.3 volts, which indicates a power production of approximately 2 mw/cm².

[0078] The actual power production will likely be slightly higher than this amount because some of the gammas from isotope layer 20 will be captured by the GaN energy conversion layer 10, and this will assist in the energy production. Approximately 15% of the

gammas are less than 10 keV, which will likely be absorbed in the GaN layer. If the isotope layer 20 is 2 cm x 3 cm, the total amount of energy that can be produced is roughly 12 mw. This is still too low to be adequate for cell phone use.

[0079] An example betavoltaic power source 6 includes between 10 and 250 layer pairs 30. This ability to combine the layer pairs 30 allows for construction of a betavoltaic power source 6 that can provide an adequate amount of electrical power for the given mobile device.

[0080] The actual thickness of energy conversion layer 10 depends upon its efficiency in capturing the particles from isotope layer 20. Typically, a thickness of about 10 microns for energy conversion layer 10 made of GaN would be sufficient to capture most of the 111 keV betas emitted from an isotope layer 20 made of (179)Ta.

[0081] In an example betavoltaic power source 6, each isotope layer 20 is 10 microns thick, and each energy conversion layer 10 is 10 microns thick, and the stacked structure has 50 layer pairs 30 that gives a total thickness of 1 mm. A typical cell phone may have a battery that is roughly 2 cm x 3 cm x 1 mm. Thus, if the remaining dimensions are 2 cm x 3 cm, then a single layer pair 30 produces approximately 12 mw of power so that 50 layer pairs 30 of GaN/(179)Ta generate roughly 600 mw of power. This is sufficient to power most cell phones and smart phones. At the end of two years, the device would still generate approximately 300 mw of power.

[0082] Notice that the betavoltaic power source 6 can also be scaled to fit within a particular type of mobile device. For example, a typical tablet device has dimensions of approximately 9" x 7". Assuming the betavoltaic power source 6 needs to have dimensions of 10 cm x 10 cm for an area of 100 cm^2 , a single layer pair 30 can produce 200 mw ($2 \text{ mw/cm}^2 \times 100 \text{ cm}^2$). By creating a stack of 50 layer pairs 30 to define a total thickness of 1 mm, 10 watts of power can be produced. This is sufficient to power a tablet device for several years. A 2 mm thick betavoltaic power source 6 formed by 100 layer pairs 30 is sufficient to power a typical laptop computer.

Radiation-absorbing shield

[0083] Depending upon the particular isotope(s) used for isotope layers 20, it may be necessary to encase at least a portion the betavoltaic power source 6 in a radiation-

absorbing material. FIG. 2 shows the betavoltaic power source 6 of FIG. 1 encased in radiation-absorbing shield 40 made of a radiation-absorbing material. An example radiation-absorbing material is stainless steel.

[0084] The thickness of the radiation-absorbing walls of shield 40 depends upon the type of radiation-absorbing material being used, as well as the energy of the radiation emitted by the isotope layers 20. For example, for isotope layers 20 made from (^{179}Ta) , the gamma emission peaks at 65 keV. In the stacked configuration of betavoltaic power source 6 of FIGS. 1 and 2, the gammas generated near the center of the stack will be absorbed by energy conversion layers 10 and isotope layers 20 before they can exit the stacked structure. However, consumers and/or other electronics will need to be substantially shielded from the gammas emitted near the edges of the stacked structure. Thus, in an example, shield 40 has walls that are 1 mm thick and made of stainless steel, which is sufficient to block the 65 keV gamma rays produced by isotope layers 20 made from (^{179}Ta) .

[0085] In an example where betavoltaic power source 6 is powered primarily with isotope layers 20 made of (^3H) (tritium), there are no emitted gammas or x-rays, and the betas have an energy upper limit of 18.6 keV. For this example, 10 micron thick GaN energy conversion layers 10 on either side of the (^3H) isotope layers 20 is sufficient to act as a shield for the betavoltaic power source 6. Since the lifetime of the (^3H) isotope is 12.6 years, the number of particles emitted per unit time is reduced considerably from (^{179}Ta) (approximately 7x slower), and the average energy of betas is about 3x lower. This implies that the average power for such a source will likely be about 20x lower than for the (^{179}Ta) source. Nevertheless, for certain mobile power applications that require low power, such a betavoltaic power source can be useful.

Heat generation and cooling

[0086] The energy conversion materials used for energy conversion layers 10 (e.g., GaN or AlGaN) are typically between 25-35% efficient. Therefore, an appreciable amount of energy emitted by isotope layers 20 is turned into heat. For high-power devices (such as laptops), it may be necessary to provide cooling conduits. Both the GaN (or AlGaN) energy conversion layers 10 and the (^{179}Ta) isotope layers 20 have good thermal conductivity.

FIG. 3 is similar to FIG. 1 and shows the addition of optional cooling conduits 50 that pass through the stack so that heat 60 generated within the stack can be drawn out of the stack through the cooling conduits and then dissipated. In an example, conduits 50 can be made of a solid material of high thermal conductivity, such as copper.

Application

[0087] During the life of betavoltaic power source 6, the emission from the isotope layers 20 will slowly decay. As the half-life of the isotope material is approached, the power generated by the betavoltaic power source 6 will drop to half of its original value. For this reason, it is desirable to configure the betavoltaic power source 6 so that it can generate sufficient power (i.e., enough area and sufficient number of layer pairs) to meet performance requirements at a select future date. For example, if 100 mw of power is needed to operate a cell phone that has a useful life of 2 years, it is desirable to make the betavoltaic power source 6 capable of providing approximately 200 mw of initial power, so that after two years, the source is still emitting sufficient power of 100 mw.

Multiple isotopes

[0088] Not all of the isotope layers 20 in betavoltaic power source 6 need to be made of the same isotope material. In an example embodiment of betavoltaic power source 6 illustrated in FIG. 4A, there is more than one type of isotope layer 20, and these different isotope layers are denoted as 20a and 20b. The different layers 20a and 20b as shown in FIG. 4A can thought of as making up a combined isotope layer 20.

[0089] This embodiment for isotope layers 20 may be desirable if the mobile device to be powered requires more power early in its life. For example, if the betavoltaic power source includes 50 layer pairs 30, one could construct half of the isotope layers 20 (say, layers 20a) from (^{179}Ta) , and half of them (say, layers 20b) from (^{68}Ge) . The (^{68}Ge) isotopes will decay more quickly and hence provide more initial power. In this way, one can tailor the energy generation profile vs. time for the particular betavoltaic power source 6. In some examples such as shown in FIG. 4A, the different isotope layers 20a and 20b can reside immediately adjacent each other, i.e., not separated by an energy conversion layer 10. In another example illustrated in FIG. 4B, the isotope layers 20a and 20b alternate in the

stacked configuration. In an example embodiment, a combination of the configurations shown in FIGS. 4A and 4B can be used.

Constant power generation

[0090] A feature of the betavoltaic power source 6 disclosed herein is that it can produce energy 100% of the time, even when the mobile device it powers is not being used. Hence, it becomes possible to generate and store energy for later use even when the mobile device itself is not in use. FIG. 5 discloses a mobile device 100 having a display 102 and that is powered by the betavoltaic power source 6 as disclosed herein. The mobile device 100 may also include a conventional battery 8 that electrically connected to and is charged by the betavoltaic power source 6.

[0091] Thus, in an example, betavoltaic power source 6 is combined with a traditional electrical source (i.e., a battery) to create a hybrid power source. The hybrid power source allows for generating power when the mobile device is not in use (for example, while the owner of the cell phone or tablet is sleeping) for use later when needed. This may allow for the betavoltaic power source 6 to be made with fewer layers and/or with a smaller area.

Example energy conversion layer

[0092] FIGS. 6A and 6B are schematic diagrams (side view and top view, respectively) of an example embodiment of a diode-based energy conversion layer 10 for betavoltaic power source 6. The energy conversion layer 10 has a top 12 and a bottom 14. FIGS. 6A and 6B illustrate an example orientation of positive and negative electrodes 120P and 120N. Energy conversion layer 10 includes a P-doped layer 10P and an N-doped layer 10N separated by a P/N junction layer 10J.

[0093] The positive and negative electrodes 120P and 120N can be positioned to allow for easy integration with isotope layers 20 (e.g., at the top and bottom of energy conversion layer 10 and on the same side, but offset, as shown). FIG. 7A and 7B are respective side views that illustrate an example embodiment of a betavoltaic power source 6 having a multilayer stack configuration. FIG. 7C is a side view of the betavoltaic power source 6 as shown electrically connected via electrical leads (wires) 104 to external device 100, such as

battery or mobile device. The plus voltage “+V” and the minus voltage “-V” are also shown with respect to leads 104.

Energy conversion layer that includes Ge

[0094] It should also be noted that energy conversion layers 10 can include or consist of Ge. Efficient Ge solar cells have been made and are similar to the device architecture needed for betavoltaic power source 6. In an example, the Ge material for energy conversion layers 10 can be (68)Ge, thereby making the energy conversion layer itself a source of both beta electrons and x-rays. In this way, space can be conserved, and more power can be generated.

[0095] FIG. 8 illustrates an example betavoltaic power source 6 made from alternating layers of (68)Ge. Such a configuration can be used for applications where the lifetime of the (68)Ge is appropriate for the application. It is noted that Ge can be used to make a diode-based energy conversion layer 10 much in the same way that GaN is used to make a diode-based energy conversion layer.

[0096] Accordingly, an example betavoltaic power source 6 can include an isotope layer 20 (e.g., a (139)Ta isotope layer) for long life, and Ge-based diodes as the energy conversion layers 10 to convert the energy from the isotope layers 20 into electricity. Note, however, that the Ge-based material making up the diode embodiment of energy conversion layer 10 can also be an isotope (e.g., (68)Ge) that creates its own electricity. This configuration allows for twice as many layers that generate energy and thus generate twice as much power as GaN diode-based configurations. This configuration also maximizes the use of available space.

[0097] It will be apparent to those skilled in the art that various modifications and variations can be made to the present disclosure without departing from the spirit and scope of the disclosure. Thus it is intended that the present disclosure cover the modifications and variations of this disclosure provided they come within the scope of the appended claims and their equivalents.

What is claimed is:

1. A betavoltaic power source for a mobile device having a useful lifetime, comprising:
a plurality of isotope layers, with each isotope layer comprising an isotope material that emits radiation as either beta particles, x-rays or gamma rays having an amount of energy that is greater than about 15 keV and less than about 200 keV, and a half-life that is between about 0.5 years and about 5 years; and
a plurality of energy conversion layers interposed between some or all the isotope layers and that receive and convert the energy from the radiation into electrical energy sufficient to power the mobile device over the useful lifetime.
2. The betavoltaic power source according to claim 1, wherein the energy conversion layers comprise GaN.
3. The betavoltaic power source according to claim 1, wherein the energy conversion layers each have a thickness of about 10 microns to 20 microns.
4. The betavoltaic power source according to claim 1, wherein the isotope material is selected from the group of isotope materials comprising: (3)H, (194)Os, (171)Tm, (179)Ta, (109)Cd, (68)Ge, (159)Ce, and (181)W.
5. The betavoltaic power source according to claim 1, further comprising a radiation-absorbing shield operably arranged to prevent the beta particles, x-rays and gamma rays from exiting the betavoltaic power source.
6. The betavoltaic power source according to claim 1, wherein adjacent isotope and energy conversion layers define layer pairs and wherein the betavoltaic power source includes between 10 and 250 layer pairs.
7. The betavoltaic power source according to claim 1, wherein the isotope layers are made of the same isotope material.

8. The betavoltaic power source according to claim 1, wherein the amount of electrical energy is at least 10 mw.
9. The betavoltaic power source according to claim 1, wherein the amount of electrical energy is at least 100 mw.
10. The betavoltaic power source according to claim 1, further including cooling conduits that remove heat from the isotope and energy conversion layers.
11. The betavoltaic power source according to claim 1, further comprising the mobile device electrically connected to the betavoltaic power source.
12. A betavoltaic power source for a mobile device having a useful lifetime, comprising:
 - a plurality of isotope layers, with each isotope layer comprising an isotope material that emits radiation having an amount of energy that is greater than about 15 keV and less than about 200 keV, and a half-life that is between about 0.5 years and about 5 years; and
 - a plurality of energy conversion layers interposed between some or all the isotope layers and that receive and convert the energy from the radiation into electrical energy of no less than 10 mw to power the mobile device over the useful lifetime.
13. The betavoltaic power source according to claim 12, wherein one or more of the energy conversion layers have a diode structure.
14. The betavoltaic power source according to claim 13, wherein the diode structure includes either GaN or Ge.
15. The betavoltaic power source according to claim 14, wherein the Ge comprises (68)Ge.

16. The betavoltaic power source according to claim 12, wherein adjacent isotope and energy conversion layers define layer pairs, and wherein the betavoltaic power source includes between 10 and 250 layer pairs.
17. The betavoltaic power source according to claim 12, wherein the isotope layers are formed from the same isotope material.
18. The betavoltaic power source according to claim 12, wherein the radiation includes at least one of beta particles, x-rays and gamma rays.
19. The betavoltaic power source according to claim 12, further comprising the mobile device electrically connected to the betavoltaic power source.
20. The betavoltaic power source according to claim 12, further comprising a conventional battery electrically connected to the betavoltaic power source.